

# APPLICATION OF ASYMMETRICAL ZINC PHTHALOCYANINES: ORGANIC FIELD EFFECT TRANSISTORS

Gülenay Tunç(⊠)<sup>1</sup>,Betül Canımkurbey<sup>2,3</sup> Ayşe Gül Gürek<sup>1</sup>

<sup>1</sup>Department of Chemistry, Gebze Technical University, 41400, Gebze, Kocaeli, Turkey.
<sup>2</sup>S. Şerefeddin Health Services Vocational School, Amasya University, Amasya, 05100, Turkey
<sup>3</sup>Central Research Laboratory, Amasya University, 05100, Amasya, Turkey

<sup>1</sup>ORCID: 0000-0002-9208-4090 <sup>2,3</sup>ORCID: 0000-0002-5938-0509 <sup>4</sup>ORCID: 0000-0001-9341-5843

Research Article Received: 31.01.2021/Accepted: 30.06.2021 (🖂) Corresponding author: gtunc@gtu.edu.tr

## ABSTRACT

Asymmetric zinc phthalocyanine (GT4), consisting of a carboxyl function attached to the Pc ring as an anchor group, was prepared according to the procedure we described previously. The structure of this molecule was elucidated by spectroscopic methods (FT -IR, MALDI-MS, UV-VIS). In this study, asymmetric Zn (II) Pc bearing a carboxylic acid group and three hexylthio groups at the peripheral positions were synthesized, and the influence of the COOH group and the positions of the hexylthio groups on the OFET performance was investigated.

Keywords: Phthalocyanine, thin film, ambipolar, OFET, carboxylic acid.



# ÖZET

Ftalosiyanin halkasına bağlayıcı grup olarak karboksilik asit fonksiyonlandırılmış asimetrik çinko ftalosiyanin (GT4) molekülü daha önce belirtilen prosedürlerimize uygun olarak hazırlanmış ve molekül yapısı spektroskopik yöntemler (FT-IR, MALDI-MS, UV-VIS) kullanılarak aydınlatılmıştır.

Bu çalışmada peripheral pozisyonda hekziltiya ve karboksilik asit grubu içeren ftalosiyanin molekülünün sentezi ve bu grupların OFET performansı üzerine etkileri araştırılmıştır.

Anahtar Kelimeler: Ftalosiyanin, ince film, OFET, karboksilik asit.

### 1. INTRODUCTION

In recent years, organic field-effect transistors (OFETs) have received increasing attention due to their potential applications [1], focusing on the low-cost deposition of materials with large-area properties on both solid and flexible substrates for diverse applications used in displays and integrated microelectronics [2]. OFETs have several excellent properties that silicon transistors do not, most notably their flexibility. Because OFETs can be fabricated at or near room temperature, they enable the fabrication of integrated circuits on plastic or other flexible substrates that would otherwise not withstand the high temperature conditions of inorganic-based devices [3]. To achieve good OFET performance, organic semiconductors, as the most important component of OFET devices, should have the following properties: a large conjugated pi system, sufficient chemical purity, good film-forming properties, and good intermolecular electronic overlap. In general, organic oligomers, polymers and some small molecules with conjugated electronic structures are among the most studied organic semiconductors for OFET applications [4].

Phthalocyanines and their derivatives have become more important in recent years with developing technology. They are also popular in scientific research due to the discovery of their application as semiconductors. Phthalocyanines (Pcs) exhibit excellent thermal and chemical stability. These aromatic molecules have very high molar absorption coefficients in the red/near-infrared (IR) region of the solar spectrum. Moreover, they have corresponding applications in various technological fields, including organic field-effect transistors, photovoltaic solar cells, liquid crystals, photodynamic therapy, chemical sensors, catalysts, and nonlinear optics, since they have a large overlap with the visible spectrum [5-7]. This versatility of use demonstrates the importance of phthalocyanine derivatives.

Organic semiconductors are of great interest because of their growing performance in optical and electronic devices [8]. One of them also organic field effect transistors. Organic field effect transistors (OFETs) are widely used in many technological applications due to their unique properties such as mechanical flexibility, light weight, transparency and low cost [9]. In this study, asymmetric Zn(II) Pc bearing one carboxylic acid group and four hexylthio groups at the peripheral positions were designed and synthesized. We investigated the influence of the carboxylic acid (COOH) group and the positions of the hexylthio groups on the OFET performance.

## 2. MATERIAL AND METHODS

All solvents and chemicals were of reagent grade and were purchased from Sigma Aldrich Chemical Co. and Merck.

Absorption spectra were recorded at room temperature on a Shimadzu UV-2600 UV-vis spectrometer using a 1 cm path length quartz cuvette between maximum range 300 and 1400 nm. Solutions were prepared in spectro-grade solvents. OFET characterization was performed using a semiconductor parameter analyzer (Keithley 4200).

### 2.1. Synthesis

The synthesis of 4-(hexylsulfanyl)-phthalonitrile (PN1) [10] and 3,4-dicyanobenzoic acid (PN2) [11] was carried out according to the literature. The synthesis of 2,9(10),16(17) tri(hexylsulfanyl)-23(24)-(carboxy) zinc(II)phthalocyanine (GT4) was shown in Scheme 1. All the synthesis data were reported in our previous study [12]

## 2.2. Device Fabrication

Before it was prepared 15% wt. PVA- solution of pure water (average molecular weight ~30). This solution was mixed at 110 °C during the day. At the same time, the ITO substrate was purified in pure water, acetone or ethanol. After the purification process, the PVA solution was spin coated onto the ITO substrate. The PVA films were annealed in a glove box at 60 °C for one day. ZnPc was also spin-coated as the active layer and annealed at 50 °C for 30 minutes. Then, silver (Ag) was deposited on the ZnPc film as a source-drain electrode (Figure 1). Keithley 4200 semiconductor characterization instrument was used for transistor characterization.



Figure 1. Basic OFET structure.

#### 3. RESULTS AND DISCUSSION

Phthalocyanine GT4 [12] was prepared according to the procedure we described previously. The synthetic route of phthalocyanine GT4 was shown in Scheme 1. Phthalocyanine GT4 (Scheme 1) was prepared by cyclotetramerization reaction of 4-(hexylsulfanyl)phthalonitrile (PN1) and 3,4-dicyanobenzoic acid (PN2) in a ratio of 9:1 in the presence of zinc chloride (ZnCl2) and heated under reflux in DMF (dimethylformamide) to 18% yield. The desired Pc was separated chromatographically from the reaction mixture.



**Scheme 1.** The synthetic pathway of GT4 (i) ZnCl2, DMF (dimethylformamide), (1,8-diazabicyclo [5.4.0] undec-7-ene) (DBU),160 °C.

The synthesized phthalocyanine derivative (GT4) was fully characterized by spectroscopic techniques such as NMR, FT -IR, mass spectrometry (MS), electronic absorption spectroscopy. The GT4 molecule showed high solubility in common organic solvents including acetone, THF, chloroform, DMSO, DMF and DCM. In the FT -IR spectra of GT4, the presence of the characteristic broad stretching vibration of carboxylic acid- OH at about 3300 cm-1 and the peak of C=O at about 1710 cm-1 observed that the formation of Pc derivatives took place. The peaks of molecular ions at m/z 971.542 [M]+ of the molecule correspond to the expected molecular structures. 1H NMR spectra were recorded in d8-THF and showed broad chemical shifts, possibly due to self-aggregation at NMR concentration. However, the integrated intensities of the signals correspond to the number of hydrogen atoms in the molecule. The UV-vis absorption spectra of the Pc molecule were carried out in dilute THF solutions ( $1 \times 10-5$  M) and shown in Figure 1, the characteristic Q bands were observed at 684 nm and the B band at 354 nm.

Tunç G., Canımkurbey B., Gürek A., (2021). Application of Asymmetrical Zinc Phthalocyanines: Organic Field Effect Transistors, Journal of Amasya University the Institute of Sciences and Technology, 2(1),31-37



**Fig. 1** Absorption spectra of **GT4** in THF ( $1 \times 10^{-5}$  M).

Figure 2 shows the output characteristic (a) and the transfer characteristic of phthalocyanine-based OFETs. The ON /OFF ratio of the OFET is about 104.

<b>Table 1.</b> Parameter of fabricated OFETS
---

Sample	Mobility (cm <sup>2</sup> /Vs)	On/Off Ratio	V <sub>Th</sub> (V)
GT4	$4,8 \times 10^{-2} \text{ cm}^2/\text{Vs}$	~10 <sup>4</sup>	-5V

The threshold voltage is around -5 V. Mobility ( $\mu_{FET}$ ) values of devices are measured by using equation below:

$$I_{DS} = \mu_{FET} \left(\frac{WC_i}{2L}\right) (V_{GS} - V_{Th})^2$$

where *L* and *W* are the length and width of the channels respectively,  $V_{Th}$  is the threshold voltage and  $C_i$  are the capacitance per unit area. As shown in the Table, the mobility calculated ~  $4.8 \times 10^{-2}$  cm<sup>2</sup>/Vs. Tunç G., Canımkurbey B., Gürek A., (2021). Application of Asymmetrical Zinc Phthalocyanines: Organic Field Effect Transistors, Journal of Amasya University the Institute of Sciences and Technology, 2(1),31-37



Figure 2. a) Output characteristic and b) Transfer characteristic of OFET

#### 4. CONCLUSIONS

In summary, an asymmetric zinc phthalocyanine (GT4) consisting of a carboxyl function attached to the Pc ring as an anchor group was developed. The asymmetric Zn (II) Pcs bearing a carboxylic acid group and four hexylthio groups at the peripheral positions were investigated for the influence of the COOH group and the positions of the hexylthio groups on the OFET performance. We observed that the increased mobility (4.8×10-2 cm2/Vs) according to the studies in the literature. [13].

#### **Conflicts of interest**

The authors declare that there are no potential conflicts of interest relevant to this article.

#### REFERENCES

- Dong S., Tian H., Huang L., Zhang J., Yan D., Geng Y., & Wang F. (2011). Non-Peripheral Tetrahexyl-Substituted Vanadyl Phthalocyanines with Intermolecular Cofacial π-π Stacking for Solution-Processed Organic Field-Effect Transistors. *Advanced Materials*, 23(25): 2850– 2854.
- Chaure N. B., Cammidge A. N., Chambrier I., Cook M. J., Ray A. K. (2015). A Tetrabenzotriazaporphyrin Based Organic Thin Film Transistor: Comparison with a Device of the Phthalocyanine Analogue. ECS *Journal of Solid-State Science and Technology*, 4(4): P3086–P3090.

- Sirringhaus H. (2005). Device physics of solution-processed organic field-effect transistors. *Advanced Materials*, 17(20), 2411-2425.
- 4. Lever ABP., Leznoff CC. (1996). Phthalocyanine: properties and applications. *Advanced Materials*, Vol. 4 p.536.
- 5. Bottari G., Torre G. de la, Guldi, D.M., Torres T. (2010). Covalent and noncovalent phthalocyanine carbon nanostructure systems: synthesis, photoinduced electron transfer, and application to molecular photovoltaics. *Chemical Reviews*, 110, 6768–6816.
- Canımkurbey B., Taşkan M. C., Demir S., Duygulu, E., Atilla D., Yuksel F. (2020). Synthesis, and Investigation of Electrical Properties of Novel Liquid-Crystal Phthalocyanines bearing triple branched alkylthio chains. *New Journal of Chemistry*, 44, 7424-7435
- Warner M., Din S., Tupitsyn I.S., Morley G.W., Stoneham A.M., Bahçıvan J.A., Wu Z., Fisher A.J., Heutz S., Kay CW., Aeppli G. (2013). Potential for spin-based information processing in a thin-film molecular semiconductor. *Nature*, 503, 504-508.
- 8. Forrest S.R. (2004). The path to ubiquitous and low-cost organic electronic appliances on plastic. *Nature*, 428,911.
- 9. Scheinert S,. Paasch G,. Hörselmann I., Herasimovich A. (2010). Low-cost submicrometer organic fieled effect transistors. *Advances in Polymer Science*, 223,155.
- Gürol İ., Ahsen V., and Bekaroğlu Ö. (1994). Synthesis of tetraalkylthio-substituted phthalocyanines and their complexation with Ag I and Pd II. J. Chem. Soc., Dalt. Trans., 0, 497–500.
- 11. Canlica M., Nyokong T. (2011). Synthesis and photophysical properties of metal free, titanium, magnesium and zinc phthalocyanines substituted with a single carboxyl and hexylthio groups. *Polyhedron*, 30, 1975–1981.
- Tunç G., Güzel E., Şişman İ., Ahsen V., Cardenas-J. G. (2019). Effect of new asymmetrical Zn(ii) phthalocyanines on the photovoltaic performance of a dye-sensitized solar cell. *New J. Chem.*, 43, 14390–14401.
- 13. L. Sun. (2015). Effect of relative nanohole position on colour purity of ultrathin plasmonic subtractive colour filters *Nanotechnology*, 26,30.